WITH OPE	SN5407, SN5417, SN7407, SN7417 HEX BUFFERS/DRIVERS N-COLLECTOR HIGH-VOLTAGE OUTPUTS SDLS032B – DECEMBER 1983 – REVISED NOVEMBER 2000
 Converts TTL Voltage Levels to MOS Levels High Sink-Current Capability Input Clamping Diodes Simplify System Design Open-Collector Driver for Indicator Lamps 	SN5407, SN5417 J OR W PACKAGE SN7407, SN7417 N PACKAGE (TOP VIEW) 1A 1 14 V _{CC} 1Y 2 13 6A 2A 3 12 6Y
 Open-Collector Driver for Indicator Lamps and Relays Inputs Fully Compatible With Most TTL Circuits 	2Y [4 11] 5A 3A [5 10] 5Y 3Y [6 9] 4A GND [7 8] 4Y
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description

These monolithic TTL hex buffers/drivers feature high-voltage open-collector outputs for interfacing with high-level circuits (such as MOS), or for driving high-current loads (such as lamps or relays), and also are characterized for use as buffers for driving TTL inputs. The SN5407 and SN7407 have minimum breakdown voltages of 30 V, and the SN5417 and SN7417 have minimum breakdown voltages of 15 V. The maximum sink current is 30 mA for the SN5407 and SN5417 and 40 mA for the SN7407 and SN7417.

These devices perform the Boolean function Y = A in positive logic.

These circuits are completely compatible with most TTL families. Inputs are diode clamped to minimize transmission-line effects, which simplifies design. Typical power dissipation is 145 mW and average propagation delay time is 14 ns.

TA	PACKAGE [†]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 70°C	PDIP – N	Tube	SN7407N	SN7407N
			SN7417N	SN7417N
–55°C to 125°C	CDIP – J	Tube	SNJ5407J	SNJ5407J
	CDIF - J Tube		SNJ5417J	SNJ5417J
	CFP – W	Tube	SNJ5407W	SNJ5407W
	CFP - W		SNJ5417W	SNJ5417W

ORDERING INFORMATION

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

logic symbol[‡]

1 4	1	\triangleright	\diamond	2	1Y
1A	3		-	4	2Y
2A	5		_	6	
3A	9			8	3Y 4Y
4A	11		_	10	5Y
5A 6A	13		_	12	6Y
04					

[‡] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



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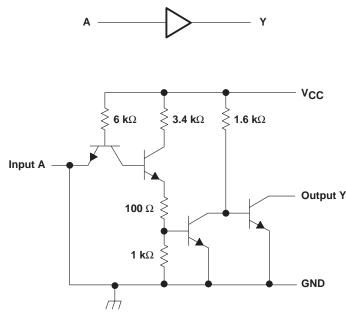
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SN5407, SN5417, SN7407, SN7417 **HEX BUFFERS/DRIVERS** WITH OPEN-COLLECTOR HIGH-VOLTAGE OUTPUTS

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schematic

logic diagram, each buffer/driver (positive logic)



Resistor values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC} Input voltage range, V _I (see Note 1)	
Output voltage, V _O (see Notes 1 and 2): SN5407, SN7407 SN5417, SN7417	30 V
Package thermal impedance, θ_{IA} (see Note 3)	
Storage temperature range, T _{stg}	

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to GND.

2. This is the maximum voltage that should be applied to any output when it is in the off state.

3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions

				NOM	MAX	UNIT
	Supply voltage	SN5407, SN5417	4.5	5	5.5	V
Vcc	Supply voltage	SN7407, SN7417	4.75	5	5.25	v
VIH	High-level input voltage		2			V
VIL	Low-level input voltage				0.8	V
Varia	High-level output voltage	SN5407, SN7407			30	V
VOH	High-level output voltage	SN5417, SN7417			15	
1.0.		SN5407, SN5417			30	mA
IOL	Low-level output current	SN7407, SN7417			40	IIIA
T Or continue for a si	Operating free air temperature	SN5407, SN5417	-55		125	°C
TA	Operating free-air temperature	SN7407, SN7417	0		70	



SN5407, SN5417, SN7407, SN7417 HEX BUFFERS/DRIVERS WITH OPEN-COLLECTOR HIGH-VOLTAGE OUTPUTS SDLS032B - DECEMBER 1983 - REVISED NOVEMBER 2000

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS [†]			TYP‡	MAX	UNIT	
VIK	$V_{CC} = MIN,$	lj = -12 mA				-1.5	V	
lou		$\lambda = 0.8 \lambda$	V _{OH} = 30 V (SN5407, SN7407)			0.25		
ЮН	$V_{CC} = MIN,$	$V_{IL} = 0.8 V$	V _{OH} = 15 V (SN5417, SN7417)			0.25	mA	
		V _{IH} = 2 V	I _{OL} = 16 mA			0.4	V	
VOL	$V_{CC} = MIN,$		I _{OL} = 30 mA (SN5407, SN5417)			0.7		
			I _{OL} = 40 mA (SN7407, SN7417)			0.7		
lj	V _{CC} = MAX,	V _I = 5.5 V				1	mA	
IIН	V _{CC} = MAX,	V _{IH} = 2.4 V				40	μA	
۱ _{IL}	V _{CC} = MAX,	$V_{IL} = 0.4 V$				-1.6	mA	
ІССН	$V_{CC} = MAX$				29	41	mA	
ICCL	V _{CC} = MAX				21	30	mA	

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

[‡] All typical values are at V_{CC} = 5 V, T_A = 25° C.

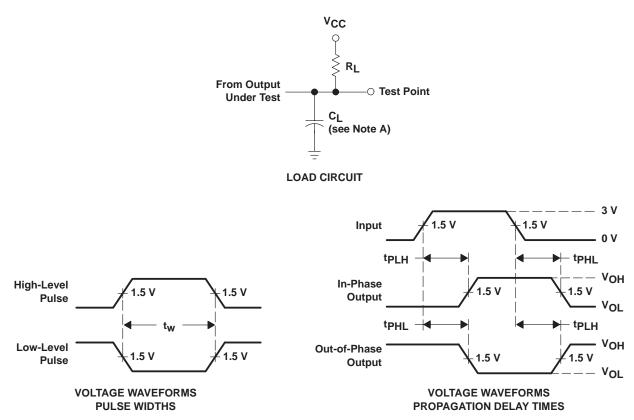
switching characteristics, $V_{CC} = 5 V$, $T_A = 25^{\circ}C$ (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS			ТҮР	MAX	UNIT
^t PLH	٨	v	D. 440.0 0.45.	F		6	10	20
^t PHL	A	ř	$R_L = 110 \Omega$, $C_L = 15 pF$	= 15 pF		20	30	ns
^t PLH	٨	v	D 450.0 0 50.	SN5407, SN5417			15	
^t PHL	A	ř	$R_{L} = 150 \Omega$, $C_{L} = 50 p$	SN5407, SN5417			26	ns



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PARAMETER MEASUREMENT INFORMATION

NOTES: A. CL includes probe and jig capacitance.

B. In the examples above, the phase relationships between inputs and outputs have been chosen arbitrarily.

C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_f \leq 7 ns, t_f \leq 7 ns.

D. The outputs are measured one at a time with one input transition per measurement.





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